

N-channel, 80 V, 1.3 mOhm, MOSFET with enhanced SOA in CCPAK1212i package

29 January 2025

**Product data sheet** 

### 1. General description

N-channel enhancement mode MOSFET in a CCPAK1212i package qualified to 175 °C. Part of Nexperia's Application Specific MOSFETs (ASFETs) for Hotswap and Soft Start. The PSMN1R2-80CSE delivers very low R<sub>DSon</sub> and enhanced safe operating area performance in a high-reliability copper-clip package (CCPAK1212i).

PSMN1R2-80CSE complements the latest "hot-swap" controllers - robust enough to withstand substantial inrush currents during turn-on, low  $R_{DSon}$  to minimize I<sup>2</sup>R losses and deliver optimum efficiency when turned fully ON.

### 2. Features and benefits

- Fully optimized Safe Operating Area (SOA) for superior linear mode operation
- Low R<sub>DSon</sub> for low I<sup>2</sup>R conduction losses
- CCPAK1212i package for applications that demand the highest performance and reliability
- Inverted package, suitable for top-side cooling
- CCPAK1212i is JEDEC listed package for open market and 2<sup>nd</sup> source compatibility

### 3. Applications

- Hot swap
- Load switch
- Soft start
- E-fuse
- Telecommunication systems based on a 48 V backplane/supply rail

### 4. Quick reference data

Table 1. Qui	ck reference data					
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C	-	-	80	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	-	-	375	А
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>	-	-	935	W
Static chara	acteristics					
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 25 °C; Fig. 11	-	1.17	1.3	mΩ
Dynamic ch	naracteristics	·	• •			
Q <sub>GD</sub>	gate-drain charge	$    I_D = 25 \text{ A}; \text{ V}_{DS} = 40 \text{ V}; \text{ V}_{GS} = 10 \text{ V}; \\     T_j = 25 \text{ °C}; \frac{\text{Fig. 13}}{\text{Fig. 14}}; \frac{\text{Fig. 14}}{\text{Fig. 14}}    $	8	27.3	63	nC

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### 5. Pinning information

Table 2	. Pinning info	rmation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source		
2	S	source		
3	S	source		
4	S	source		
5	S	source		
6	G	gate	ΙŲ Ц	
7	D	drain		
8	D	drain		G
9	D	drain		mbb076 S
10	D	drain	1 2 3 4 5 6	
11	D	drain	sot8005a_sv	
12	D	drain	CCPAK1212i (SOT8005A)	
mb	D	mounting base; connected to drain		

### 6. Ordering information

#### Table 3. Ordering information

Type number	Package								
	Name	Description	Version						
PSMN1R2-80CSE		Plastic, surface mounted copper clip package (CCPAK1212i); 12 terminals; 2.0 mm pitch, 12 mm × 12 mm × 2.5 mm body	SOT8005A						

### 7. Marking

Table 4. Marking codes								
Type number	Marking code							
PSMN1R2-80CSE	XP1E2S80C							

PSMN1R2-80CSE

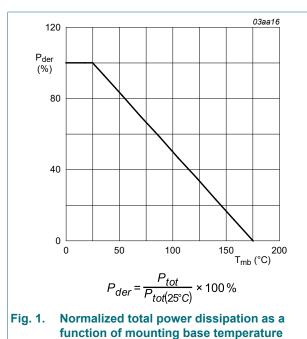
### 8. Limiting values

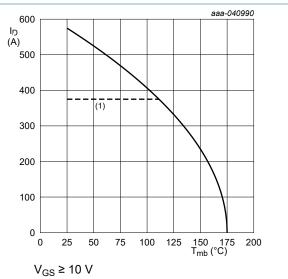
#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). T<sub>i</sub> = 25 °C unless otherwise stated.

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C		-	80	V
V <sub>DGR</sub>	drain-gate voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C; R <sub>GS</sub> = 20 kΩ		-	80	V
V <sub>GS</sub>	gate-source voltage			-20	20	V
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>		-	935	W
ID	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>		-	375	А
		V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 100 °C; <u>Fig. 2</u>		-	375	А
I <sub>DM</sub>	peak drain current	pulsed; $t_p \le 10 \ \mu s$ ; $T_{mb} = 25 \ ^{\circ}C$ ; Fig. 3		-	2236	А
T <sub>stg</sub>	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T <sub>sld(M)</sub>	peak soldering temperature			-	260	°C
Source-drain	n diode					_
I <sub>S</sub>	source current	T <sub>mb</sub> = 25 °C		-	340	А
I <sub>SM</sub>	peak source current	pulsed; t <sub>p</sub> ≤ 10 µs; T <sub>mb</sub> = 25 °C		-	2236	А
Avalanche r	uggedness				-	
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	$ \begin{array}{l} {\sf I}_{\sf D} = 109 \; {\sf A}; \; {\sf V}_{sup} \leq \; 80 \; {\sf V}; \; {\sf R}_{\sf GS} = 50 \; \Omega; \\ {\sf V}_{\sf GS} = 10 \; {\sf V}; \; {\sf T}_{j(init)} = 25 \; {\rm ^{\circ}C}; \; unclamped; \\ {\sf t}_p = 229 \; \mu s; \; \overline{{\sf Fig. 4}} \end{array} $	[1]	-	1300	mJ
I <sub>AS</sub>	non-repetitive avalanche current	$V_{sup}$ = 80 V; $V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; R <sub>GS</sub> = 50 Ω; <u>Fig. 4</u>	[1]	-	109	A
Avalanche ru E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	I <sub>D</sub> = 109 A; V <sub>sup</sub> ≤ 80 V; R <sub>GS</sub> = 50 Ω; V <sub>GS</sub> = 10 V; T <sub>j(init)</sub> = 25 °C; unclamped; t <sub>p</sub> = 229 μs; Fig. 4 V <sub>sup</sub> = 80 V; V <sub>GS</sub> = 10 V; T <sub>j(init)</sub> = 25 °C;		-	1300	

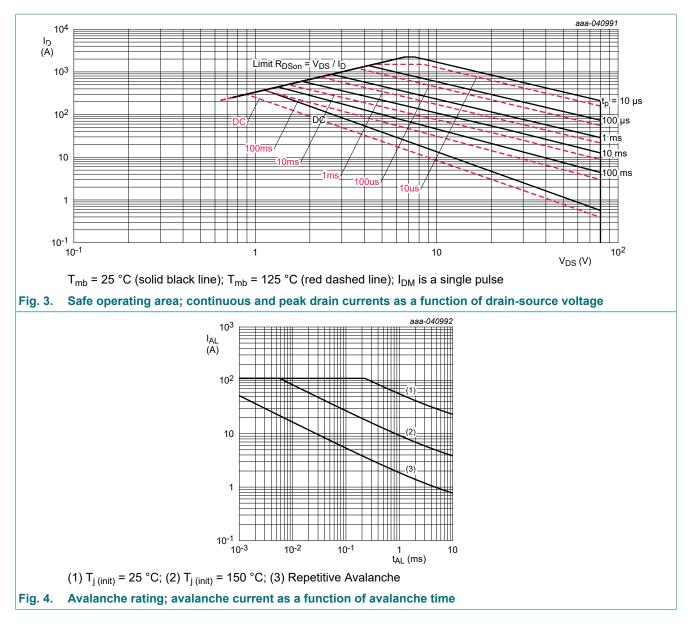
#### [1] Protected by 100% test





(1) 375 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

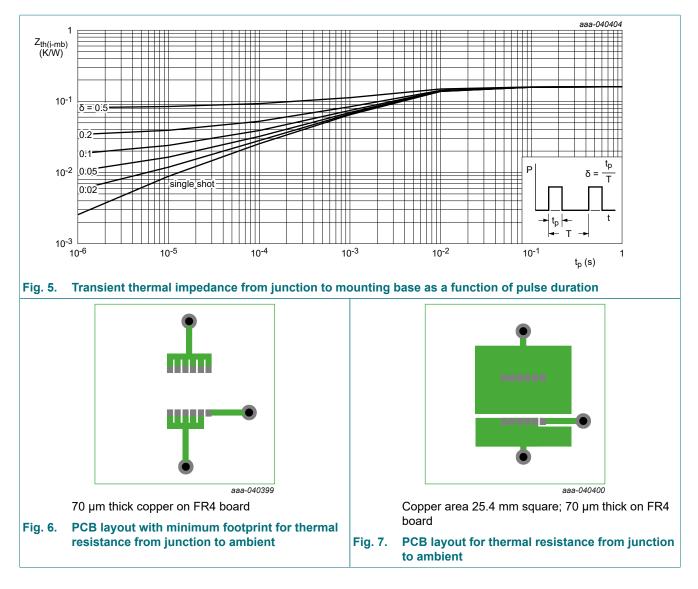
Fig. 2. Continuous drain current as a function of mounting base temperature



### 9. Thermal characteristics

### Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	<u>Fig. 5</u>	-	0.12	0.16	K/W
R <sub>th(j-a)</sub>	thermal resistance from	Fig. 6	-	58	-	K/W
	junction to ambient	<u>Fig. 7</u>	-	29	-	K/W



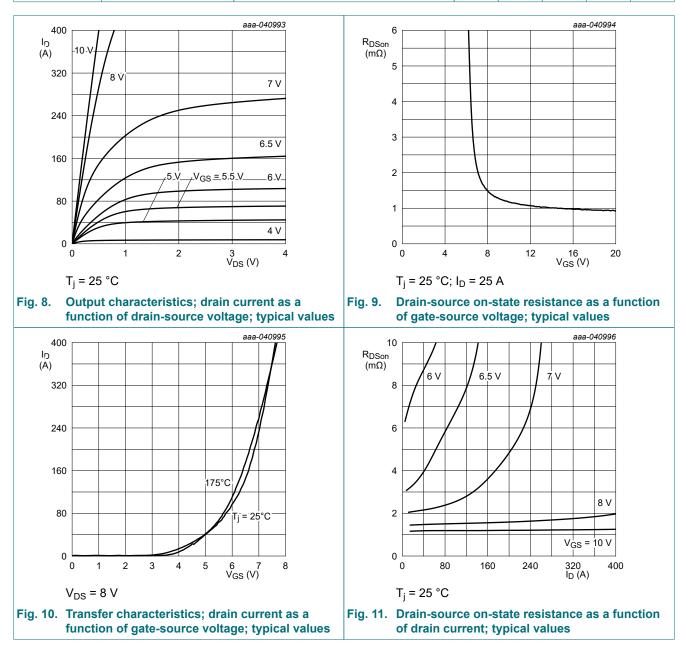
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### **10. Characteristics**

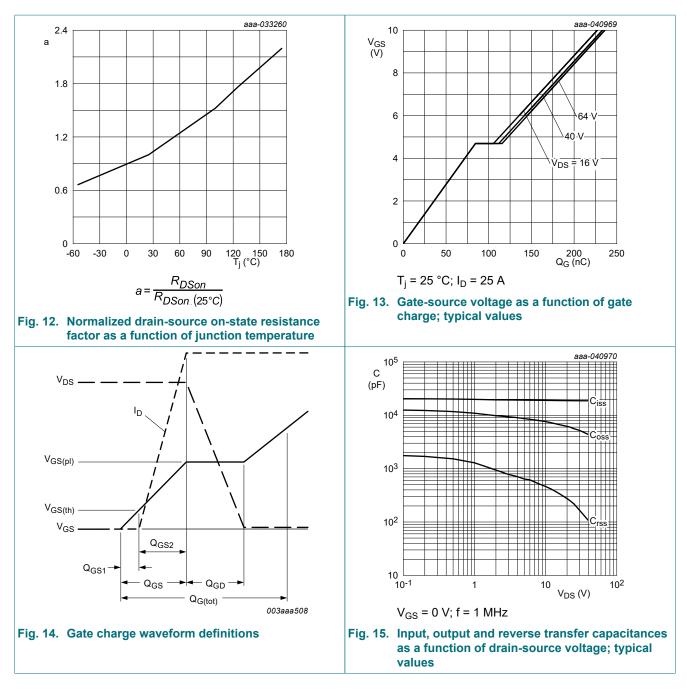
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	teristics					
V <sub>(BR)DSS</sub> drain-source		I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	80	-	-	V
( )	breakdown voltage	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>i</sub> = -55 °C	72	-	-	V
V <sub>GS(th)</sub>	gate-source threshold	I <sub>D</sub> = 1 mA; V <sub>DS</sub> =V <sub>GS</sub> ; T <sub>i</sub> = 25 °C	2	2.8	3.6	V
	voltage	I <sub>D</sub> = 1 mA; V <sub>DS</sub> =V <sub>GS</sub> ; T <sub>j</sub> = 175 °C	-	1.75	-	V
		I <sub>D</sub> = 1 mA; V <sub>DS</sub> =V <sub>GS</sub> ; T <sub>j</sub> = -55 °C	-	3.3	-	V
$\Delta V_{GS(th)} / \Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T <sub>j</sub> ≤ 150 °C	-	-6.83	-	mV/K
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = 80 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	0.13	1.6	μA
		V <sub>DS</sub> = 80 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 125 °C	-	32	160	μA
I <sub>GSS</sub>	gate leakage current	$V_{GS}$ = 20 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	2	100	nA
		V <sub>GS</sub> = -20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	2	100	nA
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 25 °C; Fig. 11	-	1.17	1.3	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 100 °C; Fig. 12	-	1.7	2	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 175 °C; Fig. 12	-	2.4	3	mΩ
R <sub>G</sub>	gate resistance	f = 1 MHz; T <sub>j</sub> = 25 °C	0.56	1.12	2.24	Ω
Dynamic cha	racteristics		I			
Q <sub>G(tot)</sub>	total gate charge	$\label{eq:ID} \begin{array}{l} I_D = 25 \text{ A}; \ V_{DS} = 40 \text{ V}; \ V_{GS} = 10 \text{ V}; \\ T_j = 25 \ ^\circ\text{C}; \ \overline{\text{Fig. 13}}; \ \overline{\text{Fig. 14}} \end{array}$	117	233	350	nC
		$I_D = 0 \text{ A}; V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V};$ $T_j = 25 \text{ °C}$	-	216	-	nC
Q <sub>GS</sub>	gate-source charge	$I_D = 25 \text{ A}; V_{DS} = 40 \text{ V}; V_{GS} = 10 \text{ V};$	51	84	118	nC
Q <sub>GS(th)</sub>	pre-threshold gate- source charge	T <sub>j</sub> = 25 °C; <u>Fig. 13; Fig. 14</u>	-	53	-	nC
Q <sub>GS(th-pl)</sub>	post-threshold gate- source charge		-	31.5	-	nC
Q <sub>GD</sub>	gate-drain charge		8	27.3	63	nC
V <sub>GS(pl)</sub>	gate-source plateau voltage	I <sub>D</sub> = 25 A; V <sub>DS</sub> = 40 V; T <sub>j</sub> = 25 °C; Fig. 13; Fig. 14	-	4.7	-	V
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 40 V; V <sub>GS</sub> = 0 V; f = 1 MHz;	11223	18705	26187	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C; <u>Fig. 15</u>	2618	4363	6981	pF
C <sub>rss</sub>	reverse transfer capacitance		11	106	319	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = 40 V; R <sub>L</sub> = 1.6 Ω; V <sub>GS</sub> = 10 V;	-	67	-	ns
t <sub>r</sub>	rise time	R <sub>G(ext)</sub> = 5 Ω; T <sub>j</sub> = 25 °C	-	57	-	ns
t <sub>d(off)</sub>	turn-off delay time	1	-	133	-	ns
t <sub>f</sub>	fall time		-	70	-	ns
Source-drain	dioda	·				

#### N-channel, 80 V, 1.3 mOhm, MOSFET with enhanced SOA in CCPAK1212i package

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t <sub>rr</sub>		$I_{S} = 25 \text{ A}; \text{ dI}_{S}/\text{dt} = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$	-	62	-	ns
Qr	recovered charge	V <sub>DS</sub> = 40 V; T <sub>j</sub> = 25 °C; <u>Fig. 17</u>	-	76.5	-	nC

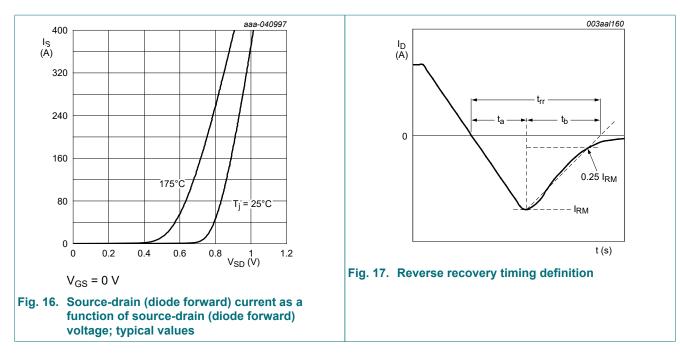


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**Product data sheet** 

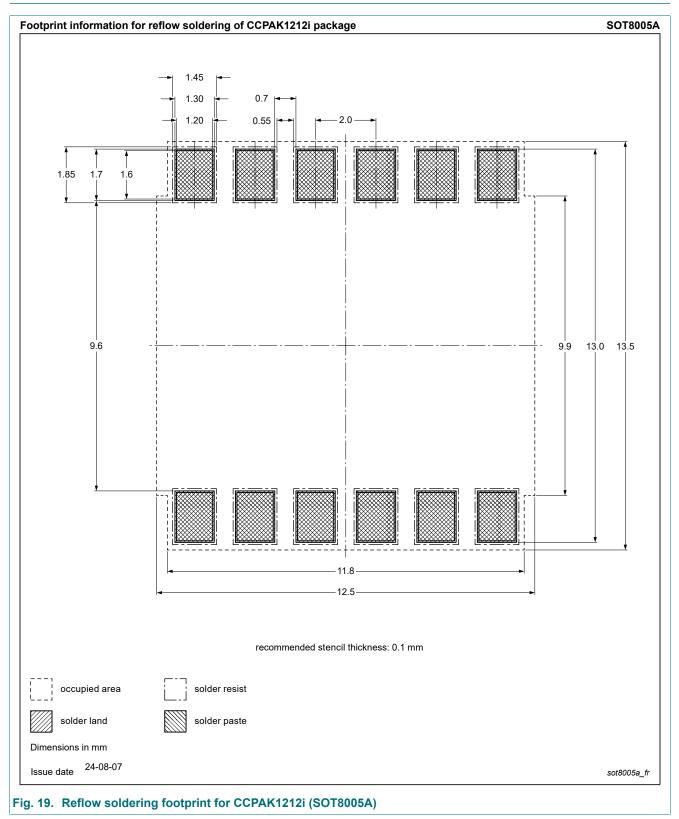
#### N-channel, 80 V, 1.3 mOhm, MOSFET with enhanced SOA in CCPAK1212i package



### 11. Package outline

T8005A: Plastic mm pitch, 12 n	nm × 12 m	m × 2.	5 mm	body												SOT80
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oosed thermal pad area																
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### 12. Soldering



### 13. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

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### Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	3
9.	Thermal characteristics	4
10.	. Characteristics	6
11.	Package outline	10
12.	. Soldering	11
13.	. Legal information	12

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